

September 1996

## 8-Bit, 20 MSPS Flash A/D Converter

### Features

- Resolution: 8-Bit  $\pm 0.3$  LSB (DNL)
- Maximum Sampling Frequency: 20 MSPS
- Low Power Consumption: 60mW (at 20 MSPS Typ) (Reference Current Excluded)
- Built-In Sample and Hold Circuit
- Built-In Reference Voltage Self Bias Circuit
- Three-State TTL Compatible Output
- Single +5V Power Supply
- Low Input Capacitance: 11pF (Typ)
- Reference Impedance: 300 $\Omega$  (Typ)
- Evaluation Board Available (HI1175-EV)
- Low Cost

### Applications

- Video Digitizing
- Image Scanners
- Multimedia
- PC Video Capture
- TV Set Top Boxes
- Personal Communication Systems (PCS)

### Description

The HI1175, CXD1175 is an 8-bit analog-to-digital converter built in a 1.4 $\mu$ m CMOS process. The low power, low differential gain and phase, high sampling rate, and single 5V supply make the HI1175, CXD1175 ideal for video and imaging applications.

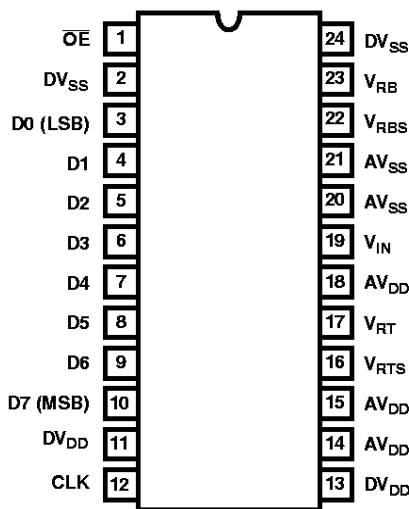
The adoption of a 2-step flash architecture achieves low power consumption (60mW) at a maximum conversion speed of 20 MSPS minimum, 35 MSPS typical with only a 2.5 clock cycle data latency. The HI1175, CXD1175 also features digital output enable/disable and a built in voltage reference. The HI1175, CXD1175 can be configured to use the internal reference or an external reference if higher precision is required.

### Ordering Information

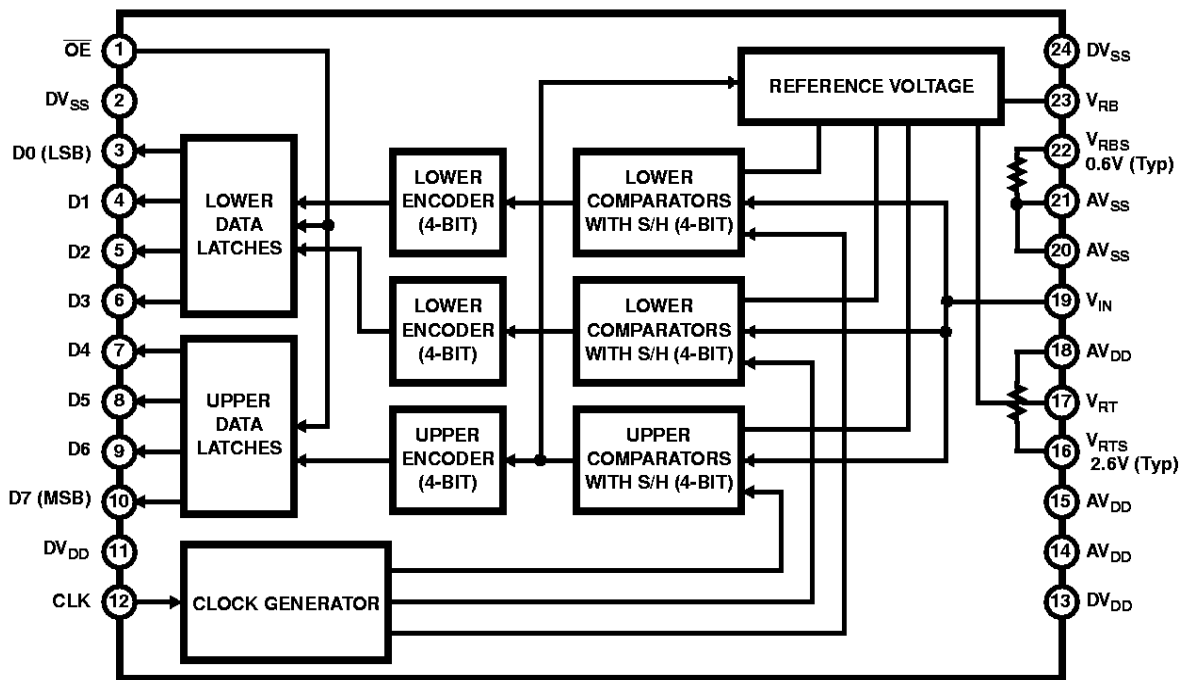
| PART NUMBER          | TEMP. RANGE    | PACKAGE            | PKG. NO. |
|----------------------|----------------|--------------------|----------|
| HI1175JCP, CXD1175AP | -20°C to +75°C | 24 Ld PDIP         | E24.4-S  |
| HI1175JCB, CXD1175AM | -20°C to +75°C | 24 Ld Plastic SOIC | M24.2-S  |

### Pinout

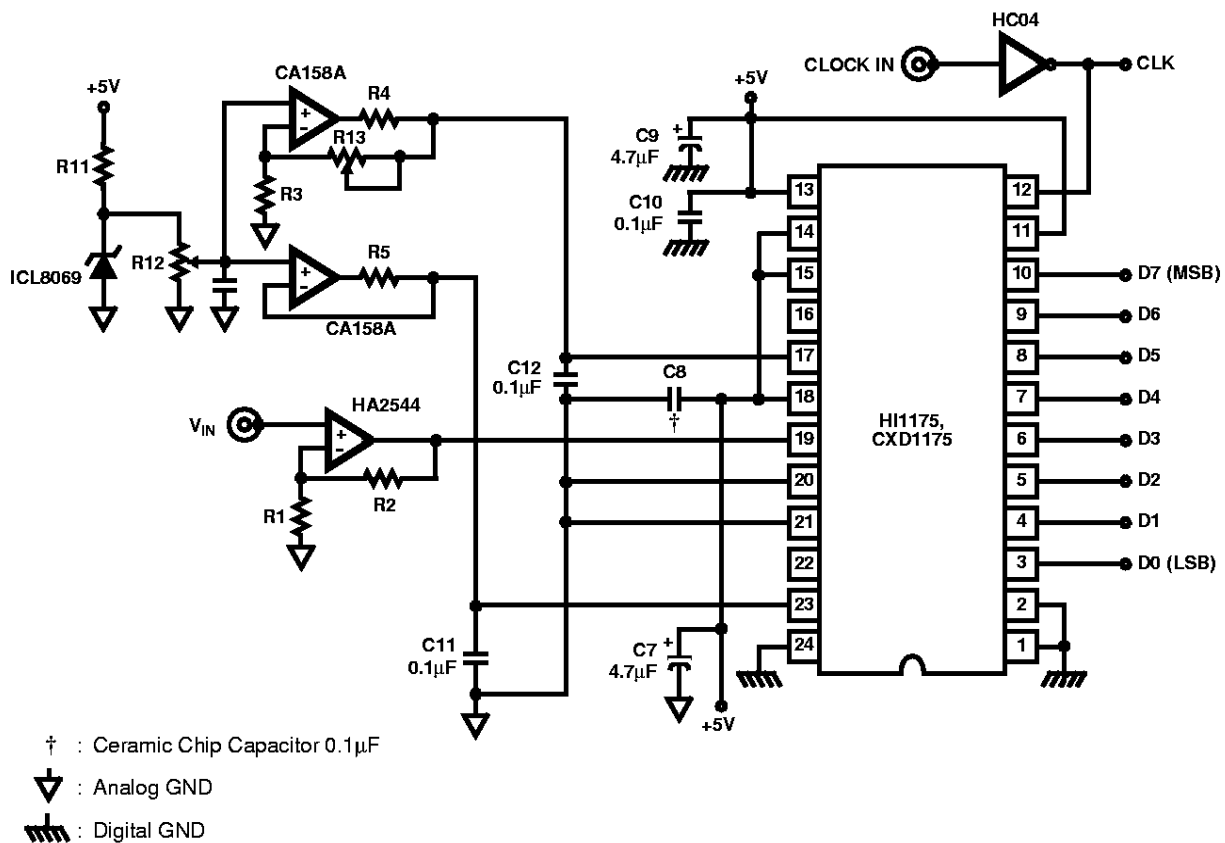
HI1175, CXD1175  
(PDIP, SOIC)  
TOP VIEW



# Functional Block Diagram



# Typical Application Schematic



NOTE: It is necessary that AV<sub>DD</sub> and DV<sub>DD</sub> pins be driven from the same supply. The gain of analog input signal can be changed by adjusting the ratio of R2 to R1.

## Specifications HI1175, CXD1175

### Absolute Maximum Ratings

Supply Voltage,  $V_{DD}$  ..... 7V  
 Reference Voltage,  $V_{RT}$ ,  $V_{RB}$  .....  $V_{DD}$  to  $V_{SS}$   
 Analog Input Voltage,  $V_{IN}$  .....  $V_{DD}$  to  $V_{SS}$   
 Digital Input Voltage,  $CLK$  .....  $V_{DD}$  to  $V_{SS}$   
 Digital Output Voltage,  $V_{OH}$ ,  $V_{OL}$  .....  $V_{DD}$  to  $V_{SS}$   
 Operating Temperature,  $T_A$  ..... -20°C to +75°C

### Thermal Information (Typical)

Thermal Resistance (Typical)  $\theta_{JA}$   
 PDIP ..... 78°C/W  
 SOIC ..... 98°C/W  
 Maximum Power Dissipation ..... 108mW  
 Maximum Junction Temperature ..... +150°C  
 Maximum Storage Temperature,  $T_{STG}$  ..... -55°C to +150°C  
 Maximum Lead Temperature ..... +300°C  
 (SOIC - Lead Tips Only) (Soldering 10s)

**CAUTION:** Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

### Operating Conditions (Note 1)

Supply Voltage  
 $AV_{DD}$ ,  $AV_{SS}$ ,  $DV_{DD}$ ,  $DV_{SS}$  ..... +4.75V to +5.25V  
 $[DGND-AGND]$  ..... 0mV to 100mV  
 Reference Input Voltage  
 $V_{RB}$  ..... 0V and Above  
 $V_{RT}$  ..... 2.8V and Below

Analog Input Range,  $V_{IN}$  .....  $V_{RB}$  to  $V_{RT}$  (1.8V<sub>P-P</sub> to 2.8V<sub>P-P</sub>)  
 Clock Pulse Width  
 $T_{PW1}$  ..... 25ns (Min)  
 $T_{PW0}$  ..... 25ns (Min)

### Electrical Specifications $F_C = 20$ MSPS, $V_{DD} = +5V$ , $V_{RB} = 0.5V$ , $V_{RT} = 2.5V$ , $T_A = +25^\circ C$ (Note 1)

| PARAMETER                                       | TEST CONDITIONS                               | MIN | TYP       | MAX       | UNIT   |
|-------------------------------------------------|-----------------------------------------------|-----|-----------|-----------|--------|
| <b>SYSTEM PERFORMANCE</b>                       |                                               |     |           |           |        |
| Offset Voltage                                  |                                               |     |           |           |        |
| $E_{OT}$                                        |                                               | -60 | -35       | -10       | mV     |
| $E_{OB}$                                        |                                               | 0   | +15       | +45       | mV     |
| Integral Non-Linearity, (INL)                   | $F_C = 20$ MSPS, $V_{IN} = 0.6V$ to 2.6V      | -   | $\pm 0.5$ | $\pm 1.3$ | LSB    |
| Differential Non-Linearity, (DNL)               | $F_C = 20$ MSPS, $V_{IN} = 0.6V$ to 2.6V      | -   | $\pm 0.3$ | $\pm 0.5$ | LSB    |
| <b>DYNAMIC CHARACTERISTICS</b>                  |                                               |     |           |           |        |
| Effective Number of Bits, ENOB                  | $f_{IN} = 1MHz$                               | -   | 7.6       | -         | Bits   |
| Spurious Free Dynamic Range                     | $f_{IN} = 1MHz$                               | -   | 51        | -         | dB     |
| Signal to Noise Ratio (SINAD)                   | $F_C = 20MHz$ , $f_{IN} = 1MHz$               | -   | 46        | -         | dB     |
| $= \frac{RMS\ Signal}{RMS\ Noise + Distortion}$ | $F_C = 20MHz$ , $f_{IN} = 3.58MHz$            | -   | 46        | -         | dB     |
| Maximum Conversion Speed, $F_C$                 | $V_{IN} = 0.6V$ to 2.6V, $F_{IN} = 1kHz$ Ramp | 20  | 35        | -         | MSPS   |
| Minimum Conversion Speed                        |                                               | -   | -         | 0.5       | MSPS   |
| Differential Gain Error, DG                     | NTSC 40 IRE Mod Ramp, $F_C = 14.3$ MSPS       | -   | 1.0       | -         | %      |
| Differential Phase Error, DP                    |                                               | -   | 0.5       | -         | Degree |
| Aperture Jitter, $t_{AJ}$                       |                                               | -   | 30        | -         | ps     |
| Sampling Delay, $t_{DS}$                        |                                               | -   | 4         | -         | ns     |
| Data Latency, $t_{LAT}$                         |                                               | -   | -         | 2.5       | Cycles |
| <b>ANALOG INPUTS</b>                            |                                               |     |           |           |        |
| Analog Input Bandwidth (-1dB), BW               |                                               | -   | 18        | -         | MHz    |
| Analog Input Capacitance, $C_{IN}$              | $V_{IN} = 1.5V + 0.07V_{RMS}$                 | -   | 11        | -         | pF     |

## Specifications HI1175, CXD1175

### Electrical Specifications $F_C = 20 \text{ MSPS}$ , $V_{DD} = +5\text{V}$ , $V_{RB} = 0.5\text{V}$ , $V_{RT} = 2.5\text{V}$ , $T_A = +25^\circ\text{C}$ (Note 1) (Continued)

| PARAMETER                                                | TEST CONDITIONS                                             | MIN                             | TYP  | MAX  | UNIT             |
|----------------------------------------------------------|-------------------------------------------------------------|---------------------------------|------|------|------------------|
| REFERENCE INPUT                                          |                                                             |                                 |      |      |                  |
| Reference Pin Current, $I_{REF}$                         |                                                             | 4.5                             | 6.6  | 8.7  | mA               |
| Reference Resistance ( $V_{RT}$ to $V_{RB}$ ), $R_{REF}$ |                                                             | 230                             | 300  | 450  | $\Omega$         |
| INTERNAL VOLTAGE REFERENCE                               |                                                             |                                 |      |      |                  |
| Self Bias Mode 1                                         | Short $V_{RB}$ and $V_{RBS}$ , Short $V_{RT}$ and $V_{RTS}$ |                                 |      |      |                  |
| $V_{RB}$                                                 |                                                             | 0.60                            | 0.64 | 0.68 | V                |
| $V_{RT} - V_{RB}$                                        |                                                             | 1.96                            | 2.09 | 2.21 | V                |
| Self Bias Mode 2, $V_{RT}$                               | $V_{RB} = \text{AGND}$ , Short $V_{RT}$ and $V_{RTS}$       | 2.25                            | 2.39 | 2.53 | V                |
| DIGITAL INPUTS                                           |                                                             |                                 |      |      |                  |
| Digital Input Voltage                                    |                                                             |                                 |      |      |                  |
| $V_{IH}$                                                 |                                                             | 4.0                             | -    | -    | V                |
| $V_{IL}$                                                 |                                                             | -                               | -    | 1.0  | V                |
| Digital Input Current                                    | $V_{DD} = \text{Max}$                                       |                                 |      |      |                  |
| $I_{IH}$                                                 |                                                             | $V_{IH} = V_{DD}$               | -    | -    | 5 $\mu\text{A}$  |
| $I_{IL}$                                                 |                                                             | $V_{IL} = 0\text{V}$            | -    | -    | 5 $\mu\text{A}$  |
| DIGITAL OUTPUTS                                          |                                                             |                                 |      |      |                  |
| Digital Output Current                                   | $\overline{OE} = V_{SS}$ , $V_{DD} = \text{Min}$            |                                 |      |      |                  |
| $I_{OH}$                                                 |                                                             | $V_{OH} = V_{DD} - 0.5\text{V}$ | -1.1 | -    | mA               |
| $I_{OL}$                                                 |                                                             | $V_{OL} = 0.4\text{V}$          | 3.7  | -    | mA               |
| Digital Output Current                                   | $\overline{OE} = V_{DD}$ , $V_{DD} = \text{Max}$            |                                 |      |      |                  |
| $I_{OZH}$                                                |                                                             | $V_{OH} = V_{DD}$               | -    | 0.01 | 16 $\mu\text{A}$ |
| $I_{OZL}$                                                |                                                             | $V_{OL} = 0\text{V}$            | -    | 0.01 | 16 $\mu\text{A}$ |
| TIMING CHARACTERISTICS                                   |                                                             |                                 |      |      |                  |
| Output Data Delay, $T_{DL}$                              |                                                             | -                               | 18   | 30   | ns               |
| POWER SUPPLY CHARACTERISTIC                              |                                                             |                                 |      |      |                  |
| Supply Current, $I_{DD}$                                 | $F_C = 20 \text{ MSPS}$ , NTSC Ramp Wave Input              | -                               | 12   | 17   | mA               |

NOTE:

1. Electrical specifications guaranteed only under the stated operating conditions.

## Timing Diagrams

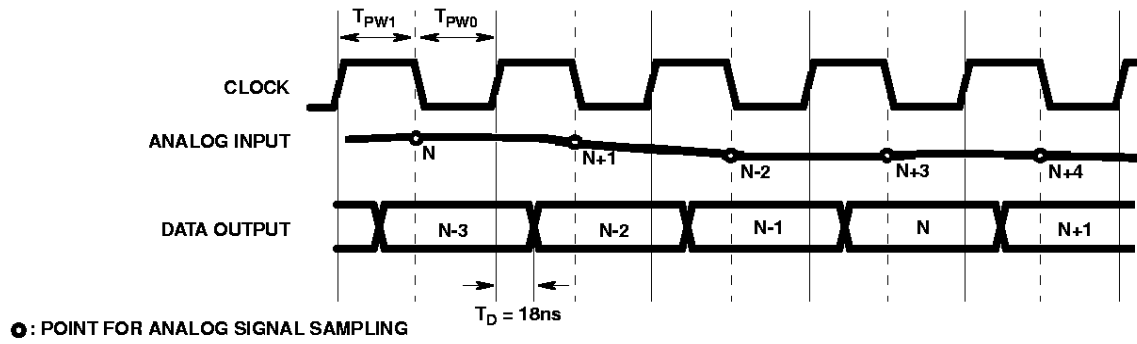


FIGURE 1.

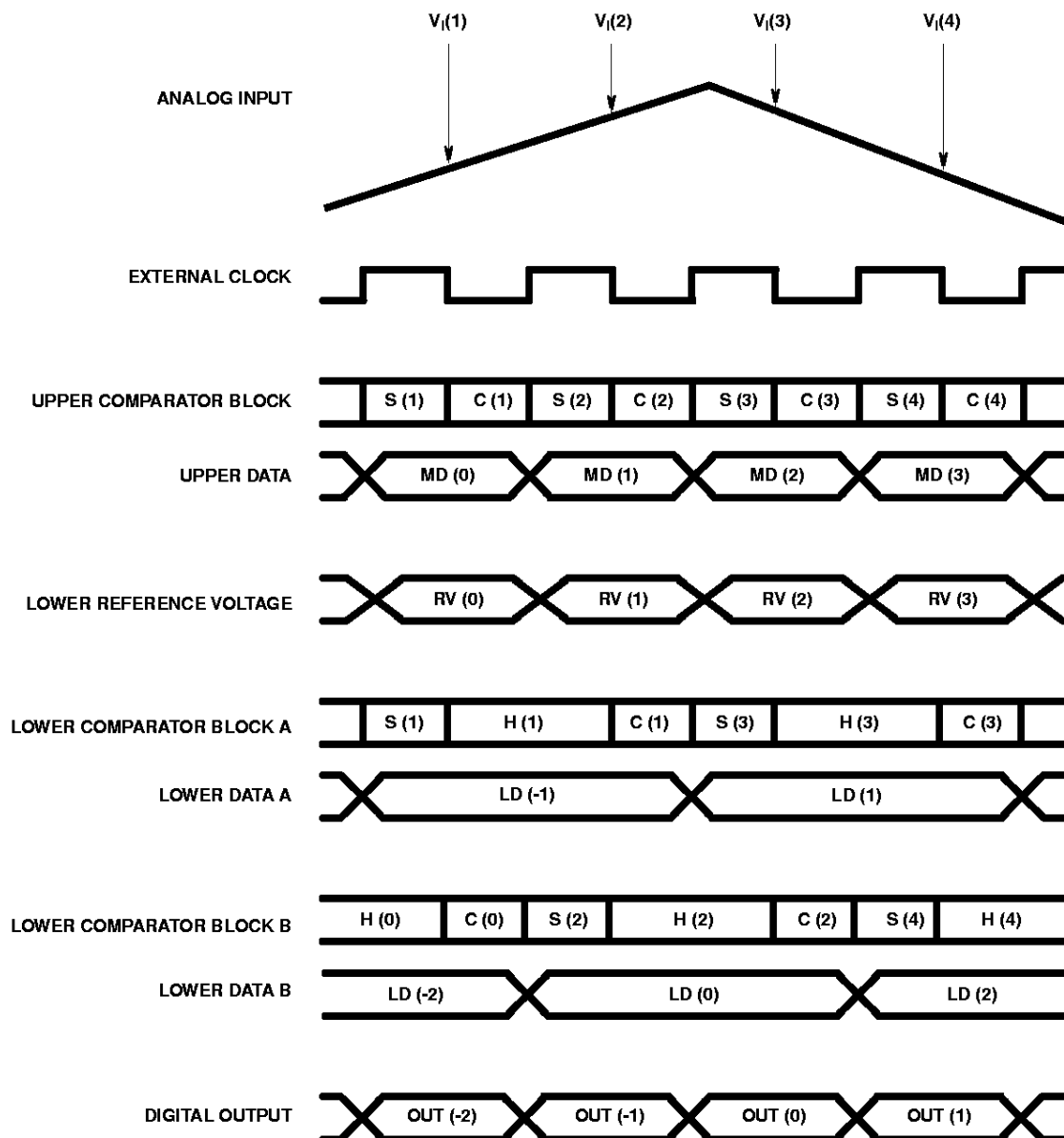


FIGURE 2.

# Typical Performance Curves

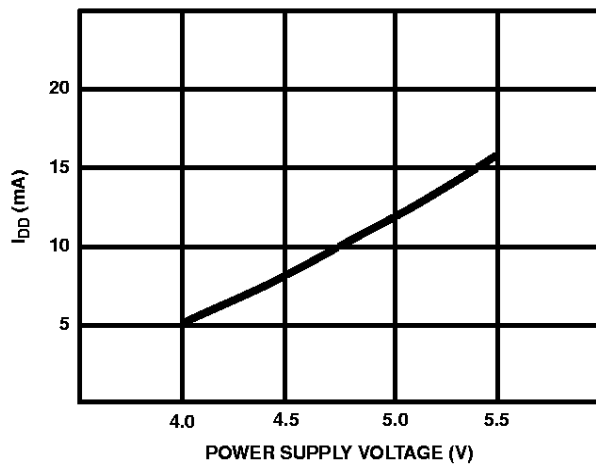


FIGURE 3. SUPPLY CURRENT vs SUPPLY VOLTAGE

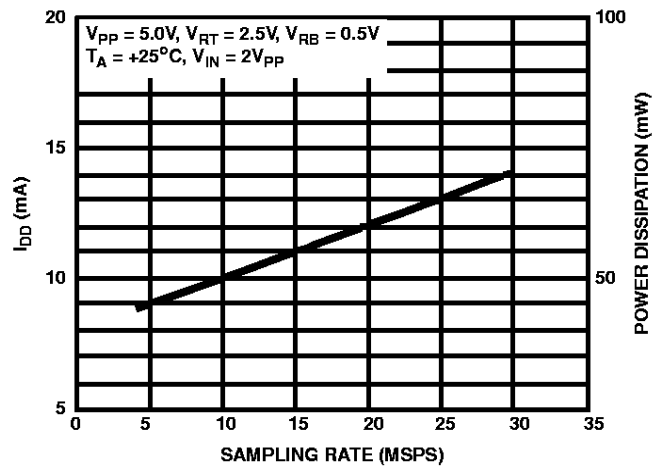


FIGURE 4. SUPPLY CURRENT AND POWER vs SAMPLING RATE

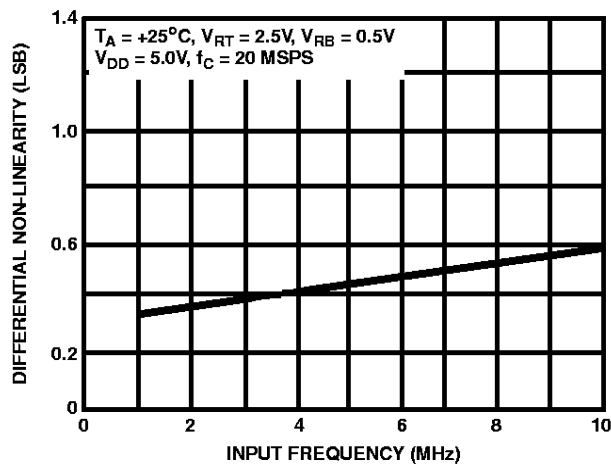


FIGURE 5. DIFFERENTIAL NON-LINEARITY vs INPUT FREQUENCY

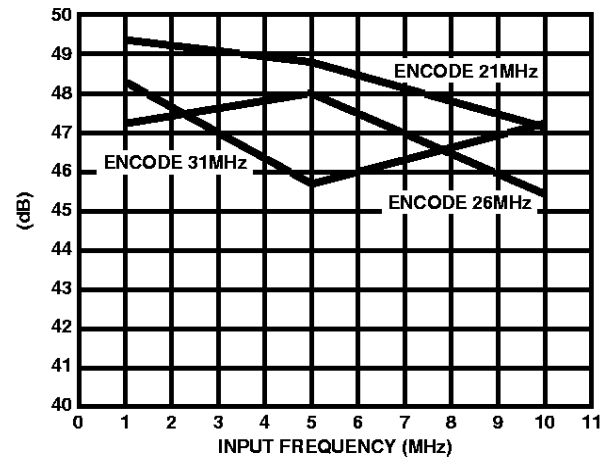


FIGURE 6. HI1175JCP, CXD1175AM SNR vs INPUT FREQUENCY

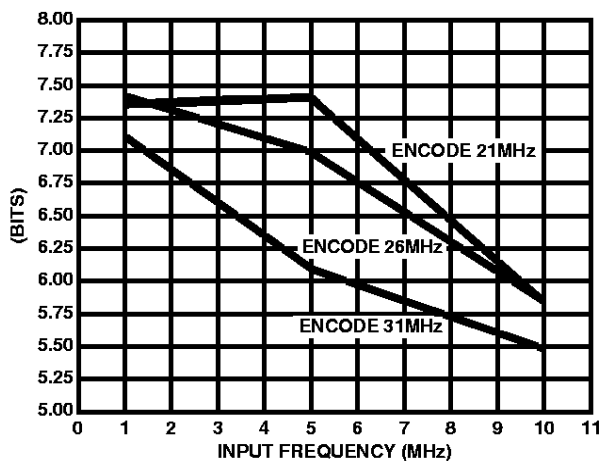


FIGURE 7. HI1175JCP, CXD1175AM ENOB vs INPUT FREQUENCY

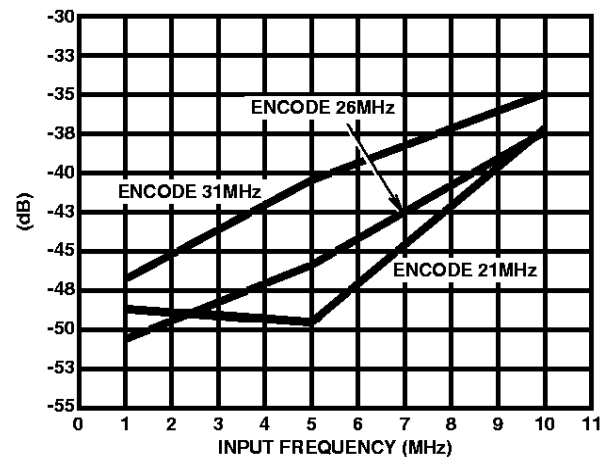


FIGURE 8. HI1175JCP, CXD1175AM THD vs INPUT FREQUENCY

Typical Performance Curves (Continued)

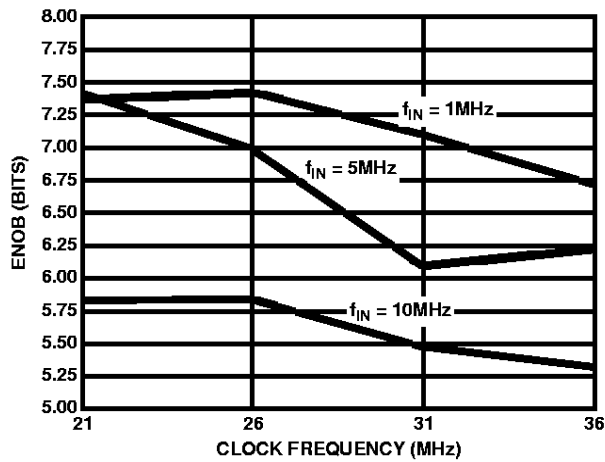


FIGURE 9. ENOB vs CLOCK FREQUENCY

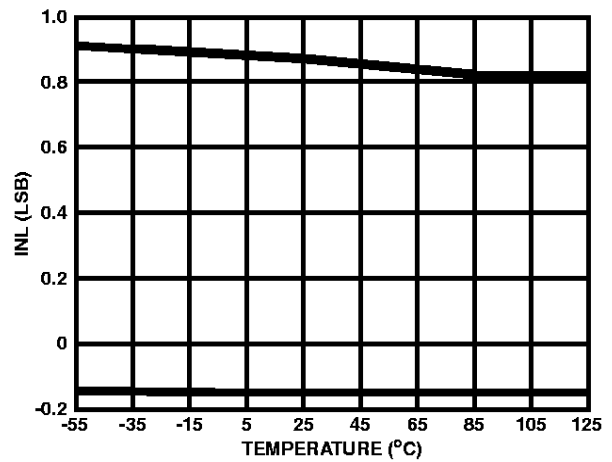


FIGURE 10. INL vs TEMPERATURE

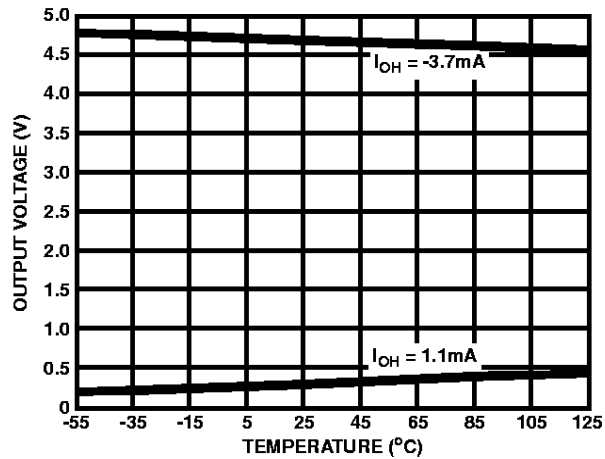


FIGURE 11. DIGITAL OUTPUT VOLTAGE vs TEMPERATURE

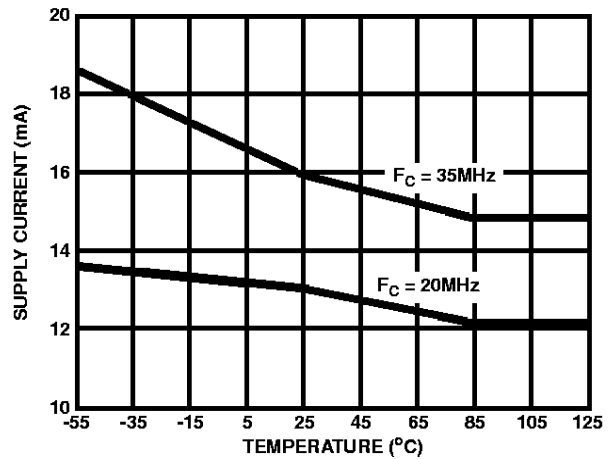


FIGURE 12. SUPPLY CURRENT vs TEMPERATURE

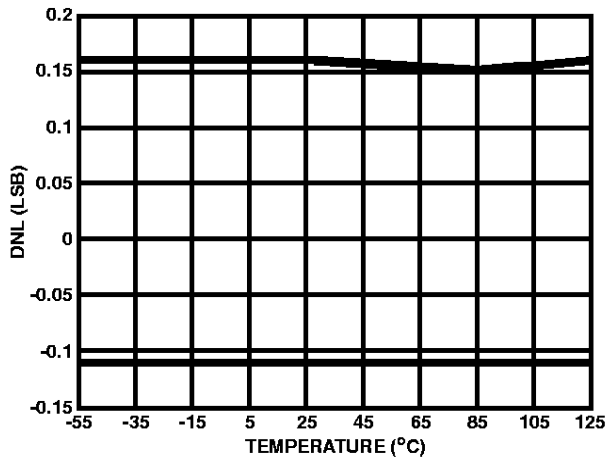


FIGURE 13. DNL vs TEMPERATURE

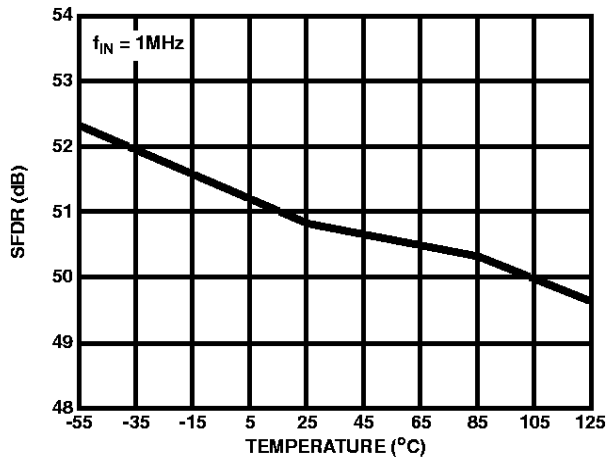


FIGURE 14. SFDR vs TEMPERATURE

Typical Performance Curves (Continued)

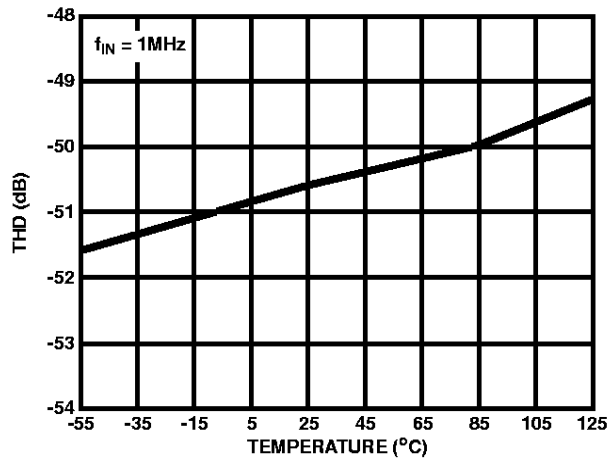


FIGURE 15. THD vs TEMPERATURE

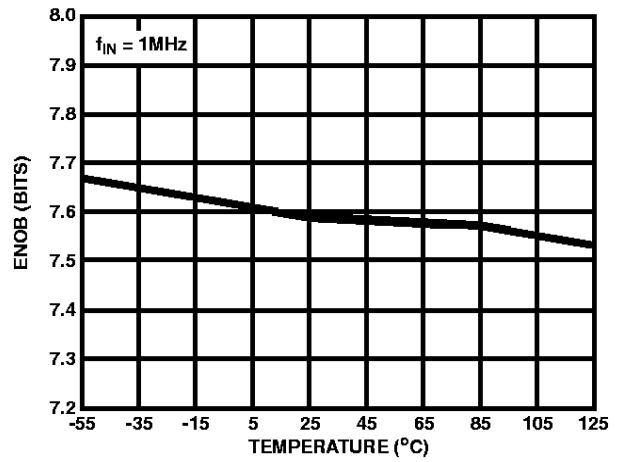


FIGURE 16. ENOB vs TEMPERATURE

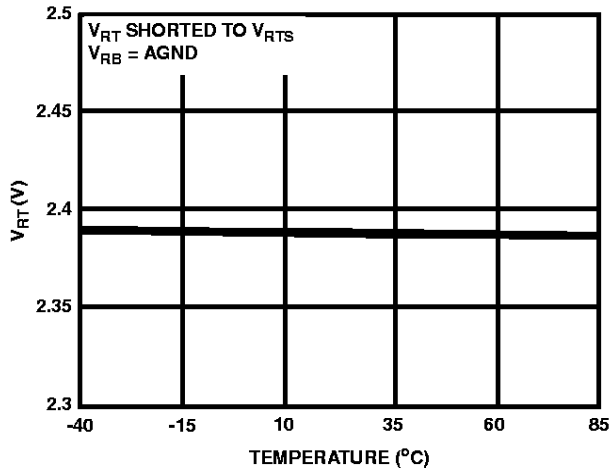


FIGURE 17. V<sub>RT</sub> vs TEMPERATURE

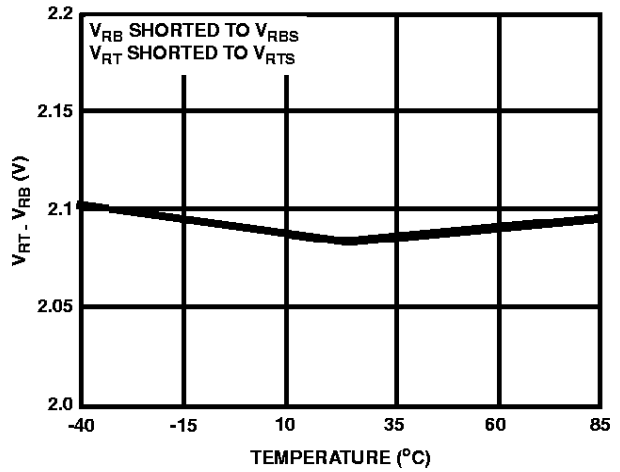


FIGURE 18. V<sub>RT</sub> - V<sub>RB</sub> vs TEMPERATURE

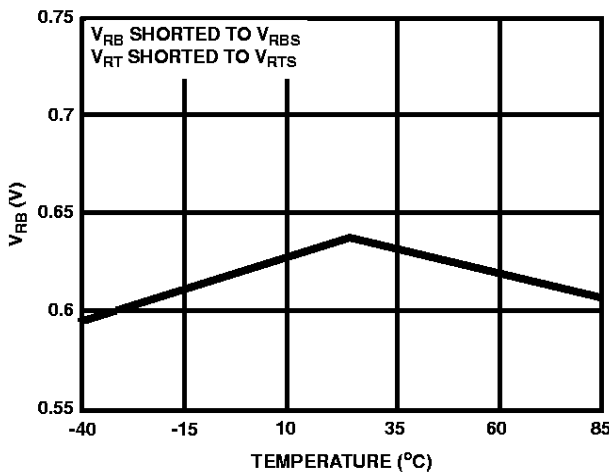


FIGURE 19. V<sub>RB</sub> vs TEMPERATURE

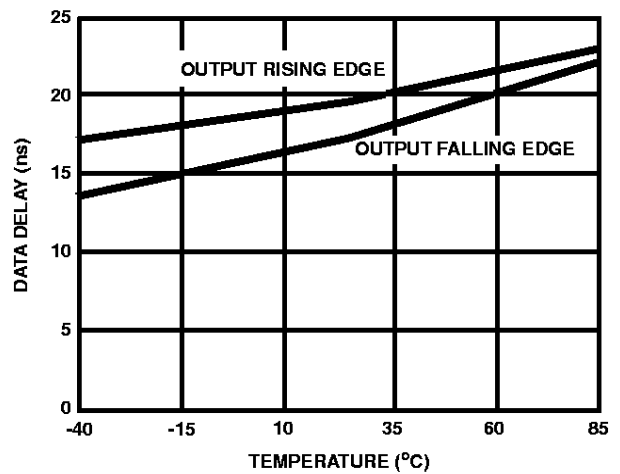
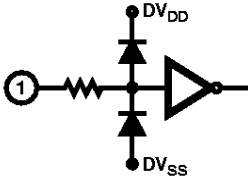
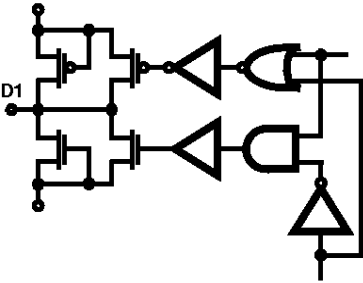
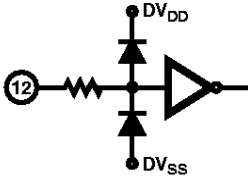
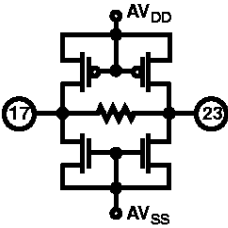
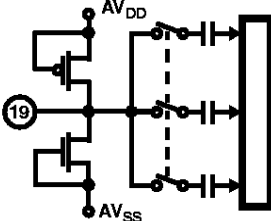


FIGURE 20. OUTPUT DATA DELAY vs TEMPERATURE



# Pin Descriptions and Equivalent Circuits

| PIN NUMBER | SYMBOL           | EQUIVALENT CIRCUIT                                                                  | DESCRIPTION                                                                                              |
|------------|------------------|-------------------------------------------------------------------------------------|----------------------------------------------------------------------------------------------------------|
| 1          | $\overline{OE}$  |    | When $\overline{OE}$ = Low, Data is valid.<br>When $\overline{OE}$ = High, D0 to D7 pins high impedance. |
| 2, 24      | DVSS             |                                                                                     | Digital GND.                                                                                             |
| 3-10       | D0 to D7         |    | D0 (LSB) to D7 (MSB) output.                                                                             |
| 11, 13     | DVDD             |                                                                                     | Digital +5V.                                                                                             |
| 12         | CLK              |   | Clock input.                                                                                             |
| 16         | V <sub>RTS</sub> |  | Shorted with V <sub>RT</sub> generates, +2.6V.                                                           |
| 17         | V <sub>RT</sub>  |  | Reference voltage (top).                                                                                 |
| 23         | V <sub>RB</sub>  |                                                                                     | Reference voltage (bottom).                                                                              |
| 14, 15, 18 | AVDD             |                                                                                     | Analog +5V.                                                                                              |
| 19         | V <sub>IN</sub>  |  | Analog input.                                                                                            |
| 20, 21     | AVSS             |                                                                                     | Analog GND.                                                                                              |
| 22         | V <sub>RBS</sub> |  | Shorted with V <sub>RB</sub> generates +0.6V.                                                            |

# HI1175, CXD1175

A/D OUTPUT CODE TABLE

| INPUT SIGNAL VOLTAGE | STEP | DIGITAL OUTPUT CODE |    |    |    |    |    |    |     |
|----------------------|------|---------------------|----|----|----|----|----|----|-----|
|                      |      | MSB                 | D6 | D5 | D4 | D3 | D2 | D1 | LSB |
| $V_{RT}$             | 255  | 1                   | 1  | 1  | 1  | 1  | 1  | 1  | 1   |
| •                    | •    |                     |    |    |    | •  |    |    |     |
| •                    | •    |                     |    |    |    | •  |    |    |     |
| •                    | •    |                     |    |    |    | •  |    |    |     |
| •                    | 128  | 1                   | 0  | 0  | 0  | 0  | 0  | 0  | 0   |
| •                    | 127  | 0                   | 1  | 1  | 1  | 1  | 1  | 1  | 1   |
| •                    | •    |                     |    |    |    | •  |    |    |     |
| •                    | •    |                     |    |    |    | •  |    |    |     |
| •                    | •    |                     |    |    |    | •  |    |    |     |
| $V_{RB}$             | 0    | 0                   | 0  | 0  | 0  | 0  | 0  | 0  | 0   |

## Detailed Description

The HI1175, CXD1175 is a 2-step A/D converter featuring a 4-bit upper comparator group and two lower comparator groups of 4 bits each. The reference voltage can be obtained from the onboard bias generator or be supplied externally. This IC uses an offset canceling type comparator that operates synchronously with an external clock. The operating modes of the part are input sampling (S), hold (H), and compare (C).

The operation of the part is illustrated in Figure 2. A reference voltage that is between  $V_{RT}$ - $V_{RB}$  is constantly applied to the upper 4-bit comparator group.  $V_I(1)$  is sampled with the falling edge of the first clock by the upper comparator block. The lower block A also samples  $V_I(1)$  on the same edge. The upper comparator block finalizes comparison data MD(1) with the rising edge of the first clock. Simultaneously the reference supply generates a reference voltage RV(1) that corresponds to the upper results and applies it to the lower comparator block A. The lower comparator block finalizes comparison data LD(1) with the rising edge of the second clock. MD(1) and LD(1) are combined and output as OUT(1) with the rising edge of the third clock. There is a 2.5 cycle clock delay from the analog input sampling point to the corresponding digital output data. Notice how the lower comparator blocks A and B alternate generating the lower data in order to increase the overall A/D sampling rate.

## Power, Grounding, and Decoupling

To reduce noise effects, separate the analog and digital grounds.

In order to avoid latchup at power up, it is necessary that  $AV_{DD}$  and  $DV_{DD}$  be driven from the same supply.

Bypass both the digital and analog  $V_{DD}$  pins to their respective grounds with a ceramic 0.1 $\mu$ F capacitor close to the pin.

## Analog Input

The input capacitance is small when compared with other flash type A/D converters. However, it is necessary to drive the input with an amplifier with sufficient bandwidth and drive capability. In order to prevent parasitic oscillation, it may be necessary to insert a low value (i.e. 0.24 $\Omega$ ) resistor between the output of the amplifier and the A/D input.

## Reference Input

The range of the A/D is set by the voltage between  $V_{RT}$  and  $V_{RB}$ . The internal bias generator will set  $V_{RTS}$  to 2.6V and  $V_{RBS}$  to 0.6V. These can be used as the part reference by shorting  $V_{RT}$  and  $V_{RTS}$  and  $V_{RB}$  to  $V_{RBS}$ . The analog input range of the A/D will now be from 0.6V to 2.6V and is referred to as Self Bias Mode 1. Self Bias Mode 2 is where  $V_{RB}$  is connected to AGND and  $V_{RT}$  is shorted to  $V_{RTS}$ . The analog input range will now be from 0V to 2.4V.

# Test Circuits

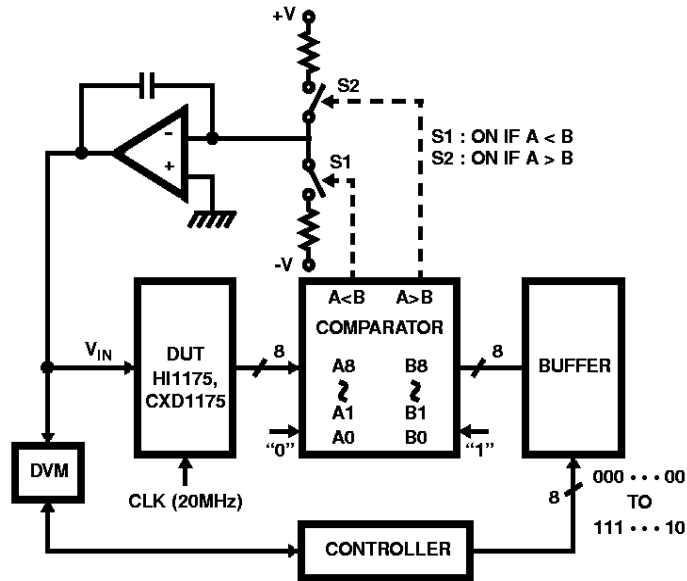


FIGURE 21. INTEGRAL AND DIFFERENTIAL NON-LINEARITY ERROR AND OFFSET VOLTAGE TEST CIRCUIT

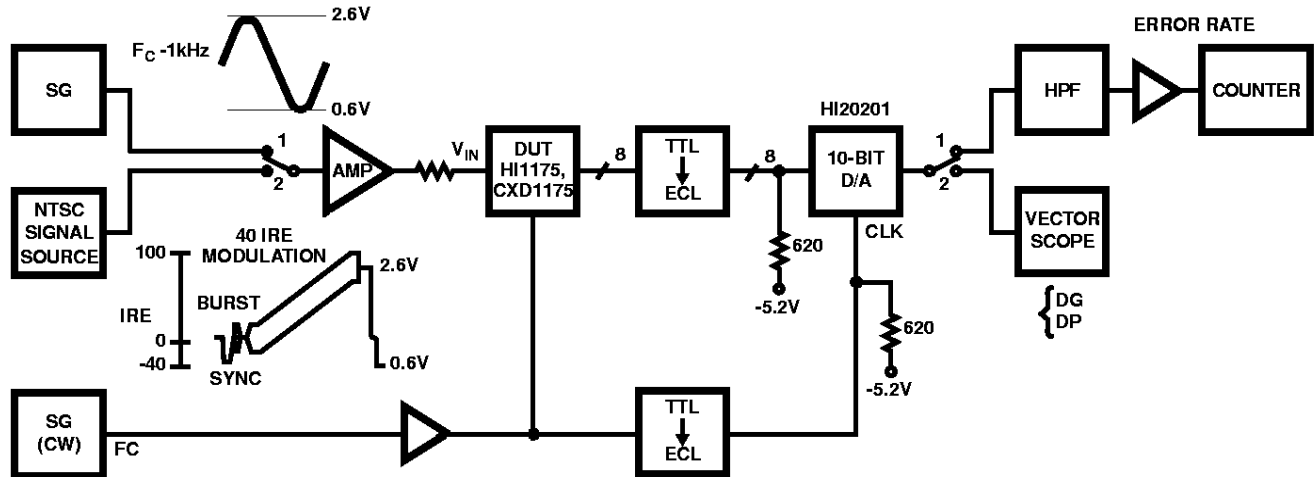


FIGURE 22. MAXIMUM OPERATIONAL SPEED AND DIFFERENTIAL GAIN AND PHASE ERROR TEST CIRCUIT

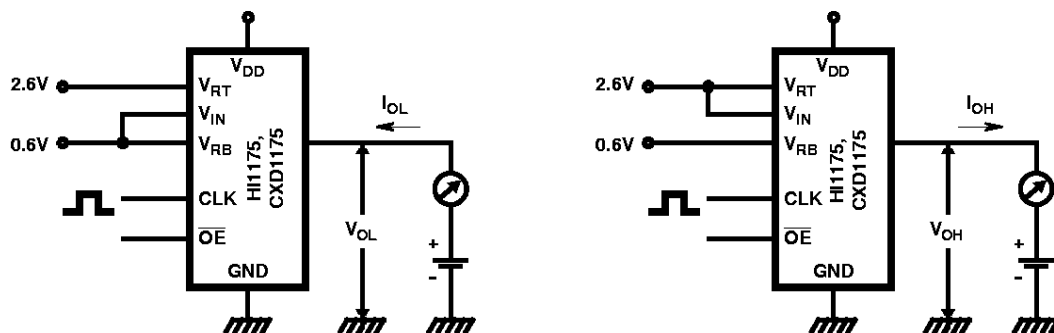
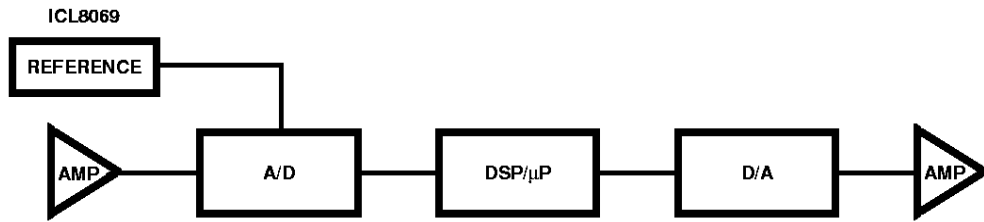


FIGURE 23. DIGITAL OUTPUT CURRENT TEST CIRCUIT

## HI1175, CXD1175



|                  |                         |          |                |                  |
|------------------|-------------------------|----------|----------------|------------------|
| HA2544 (Single)  | HI1175, CXD1175 (8-Bit) | HSP9501  | CA3338 (8-Bit) | HA5020 (Single)  |
| HA5020 (Single)  |                         | HSP48410 | HI1171 (8-Bit) | HA2842 (Single)  |
| HA5022 (Dual)    |                         | HSP48908 |                | HFA1115 (Single) |
| HA5024 (Quad)    |                         | HSP48901 |                | HFA1212 (Dual)   |
| HA5013 (Triple)  |                         | HSP48212 |                | HFA1412 (Quad)   |
| HFA1105 (Single) |                         | HSP43881 |                |                  |
| HFA1205 (Dual)   |                         | HSP43168 |                |                  |
| HFA1405 (Quad)   |                         |          |                |                  |

HSP9501: Programmable Data Buffer

HSP48410: Histogrammer/Accumulating Buffer, 10-Bit Pixel Resolution, 4K x 4K Frame Size

HSP48908: 2-D Convolver, 3 x 3 Kernel Convolution, 8-Bit

HSP48901: 3 x 3 Image Filter, 30MHz, 8-Bit

HSP48212: Video Mixer

HSP43881: Digital Filter, 30MHz, 1-D and 2-D FIR Filters

HSP43168: Dual FIR Filter, 10-Bit, 33MHz/45MHz

CMOS Logic Available in HC, HCT, AC, ACT and FCT.

HA2544: Single, 50MHz,  $I_{OUT} = 10mA$

HA2842: Single

HA5013: Triple, 125MHz,  $I_{OUT} = 20mA$

HA5020: Single, 100MHz,  $I_{OUT} = 30mA$ , Output Enable/Disable

HA5022: Dual, 125MHz,  $I_{OUT} = 20mA$ , Output Enable/Disable

HA5024: Quad, 125MHz,  $I_{OUT} = 20mA$ , Output Enable/Disable

HFA1105: Single, 350MHz,  $I_{OUT} = 60mA$

HFA1115: Single, 225MHz,  $I_{OUT} = 60mA$ , Internal Feedback Resistor

HFA1145: Single, 350MHz,  $I_{OUT} = 60mA$ , Output Enable/Disable

HFA1205: Dual, 400MHz,  $I_{OUT} = 60mA$

HFA1212: Dual, 350MHz,  $I_{OUT} = 60mA$ , Internal Feedback Resistor

HFA1412: Quad, 350MHz,  $I_{OUT} = 60mA$ , Internal Feedback Resistor

**FIGURE 24. 8-BIT SYSTEM COMPONENTS**

## Static Performance Definitions

Offset, full-scale, and gain all use a measured value of the internal voltage reference to determine the ideal plus and minus full-scale values. The results are all displayed in LSBs.

### Offset Error ( $E_{OB}$ )

The first code transition should occur at a level 1/2 LSB above the bottom reference voltage. Offset is defined as the deviation of the actual code transition from this point. Note that this is adjustable to zero.

### Full-Scale Error ( $E_{OT}$ )

The last code transition should occur for an analog input that is 1 and 1/2 LSBs below full-scale. Full-scale error is defined as the deviation of the actual code transition from this point.

### Differential Linearity Error (DNL)

DNL is the worst case deviation of a code width from the ideal value of 1 LSB. The converter is guaranteed to have no missing codes.

### Integral Linearity Error (INL)

INL is the worst case deviation of a code center from a best fit straight line calculated from the measured data.

## Dynamic Performance Definitions

Fast Fourier Transform (FFT) techniques are used to evaluate the dynamic performance of the HI1175, CXD1175. A low distortion sine wave is applied to the input, it is sampled, and the output is stored in RAM. The data is then transformed into the frequency domain with a 1024 point FFT and analyzed to evaluate the dynamic performance of the A/D. The sine wave input to the part is -0.5dB down from fullscale for all these tests. The distortion numbers are quoted in dBc (decibels with respect to carrier) and **DO NOT** include any correction factors for normalizing to fullscale.

### Signal-to-Noise Ratio (SNR)

SNR is the measured RMS signal to RMS noise at a specified input and sampling frequency. The noise is the RMS sum of all of the spectral components except the fundamental and the first five harmonics.

### Signal-to-Noise + Distortion Ratio (SINAD)

SINAD is the measured RMS signal to RMS sum of all other spectral components below the Nyquist frequency excluding DC.

### Effective Number Of Bits (ENOB)

The effective number of bits (ENOB) is derived from the SINAD data. ENOB is calculated from:

$$ENOB = (SINAD - 1.76 + V_{CORR}) / 6.02$$

where:  $V_{CORR} = 0.5dB$

### Total Harmonic Distortion

This is the ratio of the RMS sum of the first 5 harmonic components to the RMS value of the measured input signal.

### 2nd and 3rd Harmonic Distortion

This is the ratio of the RMS value of the 2nd and 3rd harmonic component respectively to the RMS value of the measured input signal.

### Spurious Free Dynamic Range (SFDR)

SFDR is the ratio of the fundamental RMS amplitude to the RMS amplitude of the next largest spur or spectral component. If the harmonics are buried in the noise floor it is the largest peak.

### Full Power Input Bandwidth

Full power bandwidth is the frequency at which the amplitude of the digitally reconstructed output has decreased 3dB below the amplitude of the input sine wave. The input sine wave has a peak-to-peak amplitude equal to the reference voltage. The bandwidth given is measured at the specified sampling frequency.

## Timing Definitions

### Sampling Delay ( $t_{SD}$ )

Sampling delay is the time delay between the external sample command (the falling edge of the clock) and the time at which the signal is actually sampled. This delay is due to internal clock path propagation delays.

### Aperture Jitter ( $t_{AJ}$ )

This is the RMS variation in the sampling delay due to variation of internal clock path delays.

### Data Latency ( $t_{LAT}$ )

After the analog sample is taken, the data on the bus is available after 2.5 cycles of the clock. This is due to the architecture of the converter where the data has to ripple through the stages. This delay is specified as the data latency. After the data latency time, the data representing each succeeding sample is output at the following clock pulse. The digital data lags the analog input by 2.5 cycles.

### Output Data Delay ( $t_D$ )

Output Data Delay is the delay time from when the data is valid (rising clock edge) to when it shows up at the output bus. This is due to internal delays at the digital output.

# Dual-In-Line Plastic Packages (PDIP)

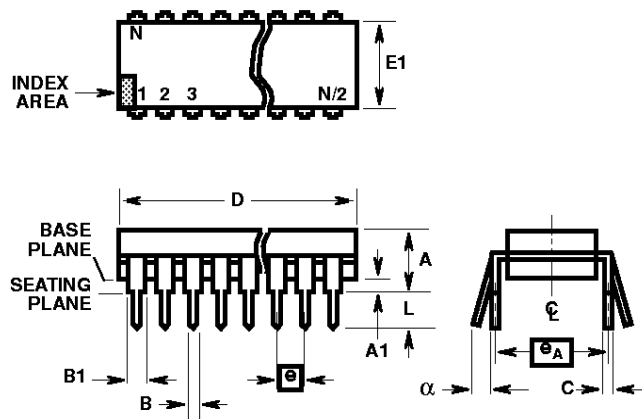


FIGURE 1

## NOTES:

1. Controlling Dimensions: MILLIMETER. In case of conflict between English and Metric dimensions, the metric dimensions control.
2. Dimensions A, A1 and L are measured with the package seated in JEDEC seating plane gauge GS-3.
3. D and E1 dimensions do not include mold flash or protrusions.
4.  $e_A$  is measured with the leads constrained to be perpendicular to base plane.
5. N is the maximum number of terminal positions.

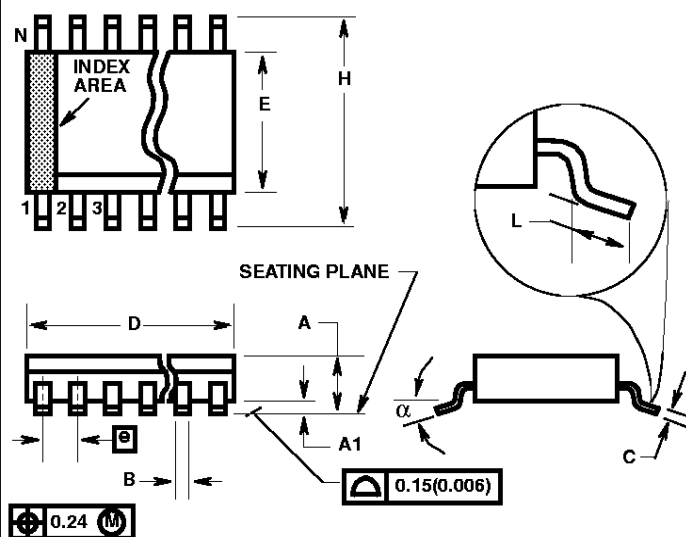
## E24.4-S

### 24 LEAD DUAL-IN-LINE PLASTIC PACKAGE (400 MIL)

| SYMBOL   | INCHES    |       | MILLIMETERS |       | NOTES |
|----------|-----------|-------|-------------|-------|-------|
|          | MIN       | MAX   | MIN         | MAX   |       |
| A        | 0.142     | 0.161 | 3.60        | 4.10  | 2     |
| A1       | 0.020     | -     | 0.50        | -     | 2     |
| B        | 0.016     | 0.023 | 0.40        | 0.60  | -     |
| B1       | 0.042     | 0.053 | 1.05        | 1.35  | -     |
| C        | 0.008     | 0.013 | 0.20        | 0.35  | -     |
| D        | 1.185     | 1.204 | 30.10       | 30.60 | 3     |
| E1       | 0.331     | 0.346 | 8.40        | 8.80  | 3     |
| e        | 0.100 BSC |       | 2.54 BSC    |       | -     |
| $e_A$    | 0.400 BSC |       | 10.16 BSC   |       | 4     |
| L        | 0.119     | -     | 3.0         | -     | 2     |
| N        | 24        |       | 24          |       | 5     |
| $\alpha$ | 0°        | 15°   | 0°          | 15°   | -     |

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## Small Outline Plastic Packages (SOIC)



### NOTES:

1. Dimension "D" does not include mold flash, protrusions or gate burrs.
2. Dimension "E" does not include interlead flash or protrusions.
3. "L" is the length of terminal for soldering to a substrate.
4. "N" is the number of terminal positions.
5. Terminal numbers are shown for reference only.
6. Controlling dimension: MILLIMETER. Converted inch dimensions are not necessarily exact.

### M24.2-S

#### 24 LEAD SMALL OUTLINE PLASTIC PACKAGE (200 MIL)

| SYMBOL   | INCHES    |       | MILLIMETERS |      | NOTES |
|----------|-----------|-------|-------------|------|-------|
|          | MIN       | MAX   | MIN         | MAX  |       |
| A        | 0.067     | 0.088 | 1.70        | 2.25 | -     |
| A1       | 0.002     | 0.011 | 0.05        | 0.30 | -     |
| B        | 0.014     | 0.021 | 0.35        | 0.55 | -     |
| C        | 0.006     | 0.011 | 0.15        | 0.30 | -     |
| D        | 0.587     | 0.606 | 14.9        | 15.4 | 1     |
| E        | 0.205     | 0.220 | 5.2         | 5.6  | 2     |
| e        | 0.050 BSC |       | 1.27 BSC    |      | -     |
| H        | 0.296     | 0.326 | 7.5         | 8.3  | -     |
| L        | 0.012     | 0.027 | 0.30        | 0.70 | 3     |
| N        | 24        |       | 24          |      | 4     |
| $\alpha$ | 0°        | 10°   | 0°          | 10°  | -     |

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